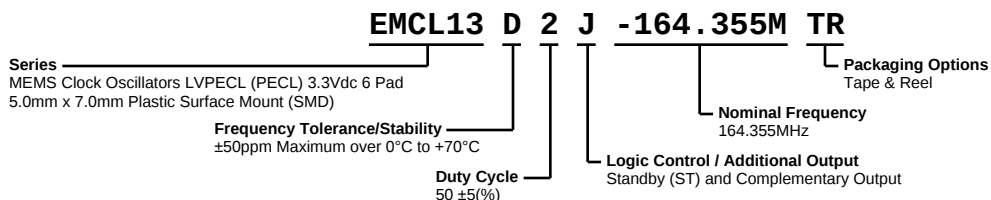


EMCL13D2J-164.355M TR



ELECTRICAL SPECIFICATIONS

Nominal Frequency	164.355MHz
Frequency Tolerance/Stability	± 50 ppm Maximum over 0°C to +70°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Reflow, Shock, and Vibration)
Aging at 25°C	± 1 ppm First Year Maximum
Supply Voltage	+3.3Vdc ± 0.3 Vdc
Input Current	80mA Maximum (Excluding Load Termination Current)
Output Voltage Logic High (Voh)	Vdd-1.10Vdc Minimum, 2.40Vdc Typical, Vdd-0.70Vdc Maximum
Output Voltage Logic Low (Vol)	Vdd-2.0Vdc Minimum, 1.60Vdc Typical, Vdd-1.40Vdc Maximum
Rise/Fall Time	150pSec Typical, 300pSec Maximum (Measured over 20% to 80% of waveform)
Duty Cycle	50 ± 5 (%) (Measured at 50% of waveform)
Output Swing (VOpp)	600mVdc Minimum, 800mVdc Typical, 1000mVdc Maximum
Load Drive Capability	50 Ohms into Vdd-2.0Vdc
Output Logic Type	LVPECL
Logic Control / Additional Output	Standby (ST) and Complementary Output
Output Control Input Voltage	Vih of 70% of Vdd Minimum or No Connect to Enable Output and Complementary Output, Vil of 30% of Vdd Maximum to Disable Output and Complementary Output (High Impedance)
Standby Current	30 μ A Maximum (Without Load)
Period Jitter (Deterministic)	0.2pSec Typical
Period Jitter (Random)	2.0pSec Typical
Period Jitter (RMS)	1.5pSec Typical, 3.0pSec Maximum
Period Jitter (pk-pk)	20pSec Typical, 25pSec Maximum
RMS Phase Jitter (Fj = 637kHz to 10MHz; Random)	1.6pSec Typical
RMS Phase Jitter (Fj = 1MHz to 20MHz; Random)	0.7pSec Typical
RMS Phase Jitter (Fj = 1.875MHz to 20MHz; Random)	0.4pSec Typical
Start Up Time	10mSec Maximum
Storage Temperature Range	-55°C to +125°C

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

ESD Susceptibility	MIL-STD-883, Method 3015, Class 2, HBM 2000V
Flammability	UL94-V0
Mechanical Shock	MIL-STD-883, Method 2002, Condition G, 30,000G
Moisture Resistance	MIL-STD-883, Method 1004
Moisture Sensitivity Level	J-STD-020, MSL 1
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K
Resistance to Solvents	MIL-STD-202, Method 215
Solderability	MIL-STD-883, Method 2003 (Six I/O Pads on bottom of package only)
Temperature Cycling	MIL-STD-883, Method 1010, Condition B
Thermal Shock	MIL-STD-883, Method 1011, Condition B
Vibration	MIL-STD-883, Method 2007, Condition A, 20G

EMCL13D2J-164.355M TR

MECHANICAL DIMENSIONS (all dimensions in millimeters)



PIN	CONNECTION
1	Standby (ST)
2	No Connect
3	Case Ground
4	Output
5	Complementary Output
6	Supply Voltage

LINE	MARKING
1	XXXX or XXXXX XXXX or XXXXX=Ecliptek Manufacturing Identifier

Note A: Center paddle is connected internally to oscillator ground (Pad 3).

Suggested Solder Pad Layout

All Dimensions in Millimeters



All Tolerances are ± 0.1

EMCL13D2J-164.355M TR

OUTPUT WAVEFORM & TIMING DIAGRAM



EMCL13D2J-164.355M TR

OUTPUT WAVEFORM & TIMING DIAGRAM



EMCL13D2J-164.355M TR

Test Circuit for Output Enable and Complementary Output



Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less than 2mm) to the package ground and supply voltage pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>500MHz) passive probe is recommended.

Note 3: Test circuit PCB traces need to be designed for a characteristic line impedance of 50 ohms.

EMCL13D2J-164.355M TR

Test Circuit for Standby and Complementary Output



Note 1: An external $0.01\mu\text{F}$ ceramic bypass capacitor in parallel with a $0.1\mu\text{F}$ high frequency ceramic bypass capacitor close (less than 2mm) to the package ground and supply voltage pin is required.

Note 2: A low capacitance ($<12\text{pF}$), 10X attenuation factor, high impedance ($>10\text{Mohms}$), and high bandwidth ($>500\text{MHz}$) passive probe is recommended.

Note 3: Test circuit PCB traces need to be designed for a characteristic line impedance of 50 ohms.

Technical drawing of a metal part, showing front and side views with dimensions and tolerances.

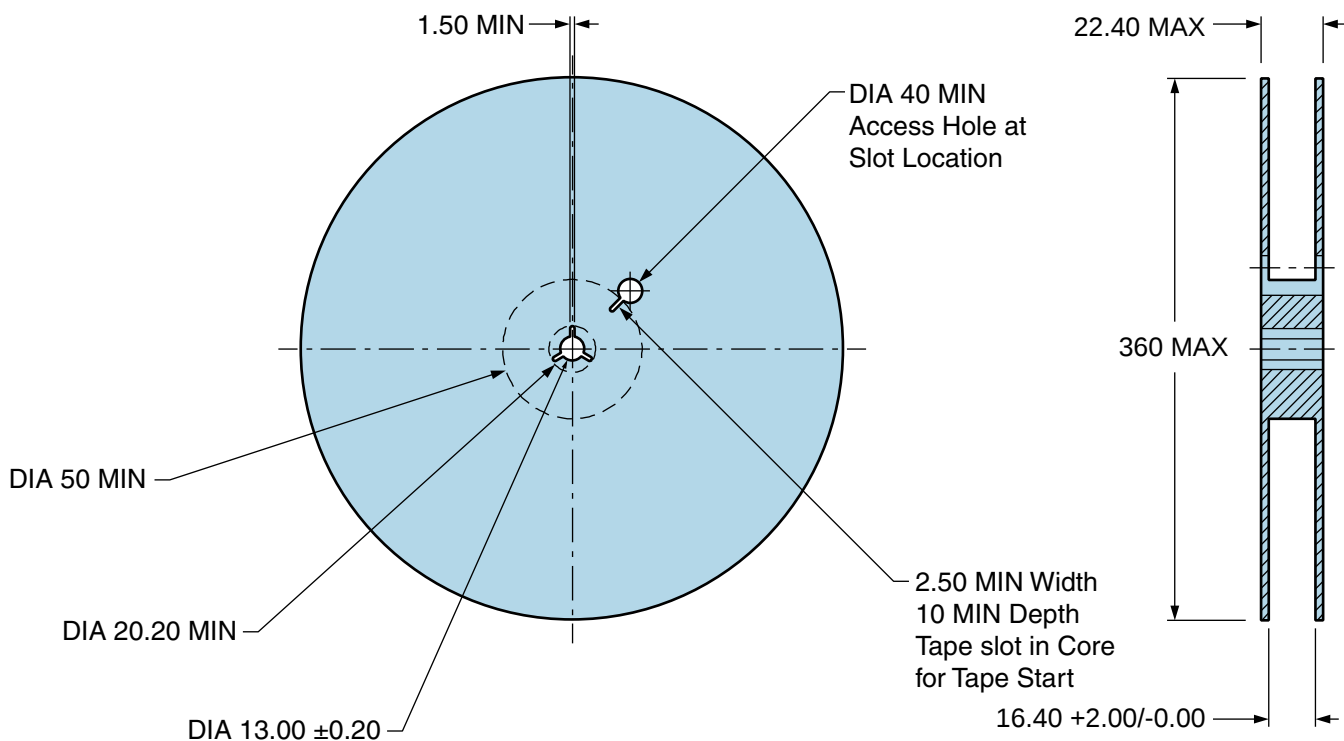
Front View Dimensions:

- Overall width: 16.00 ± 0.30
- Overall height: 7.50 ± 0.10
- Top edge width (left to center): 4.00 ± 0.10
- Top edge width (center to right): 2.00 ± 0.10
- Bottom edge width (left to center): 8.00 ± 0.10
- Bottom edge width (center to right): $A0$
- Distance from top edge to center of bottom hole: 1.50 MIN
- Distance from top edge to center of top hole: 1.75 ± 0.10
- Distance from right edge to center of bottom hole: $B0$
- Distance from right edge to center of top hole: 0.10 MAX
- Distance from right edge to center of top hole: 0.60 MAX
- Distance from right edge to center of top hole: $K0$
- Top hole diameter: $\text{DIA } 1.50 + 0.10/-0.00$
- Bottom hole diameter: 1.50 MIN
- Marking: MARKING ORIENTATION

Side View Dimensions:

- Overall height: 7.50 ± 0.10
- Overall width: 16.00 ± 0.30
- Distance from top edge to center of bottom hole: 1.50 MIN
- Distance from top edge to center of top hole: 1.75 ± 0.10
- Distance from right edge to center of bottom hole: $B0$
- Distance from right edge to center of top hole: 0.10 MAX
- Distance from right edge to center of top hole: 0.60 MAX
- Distance from right edge to center of top hole: $K0$

Direction of Unreeling: Indicated by a large black arrow pointing to the right.



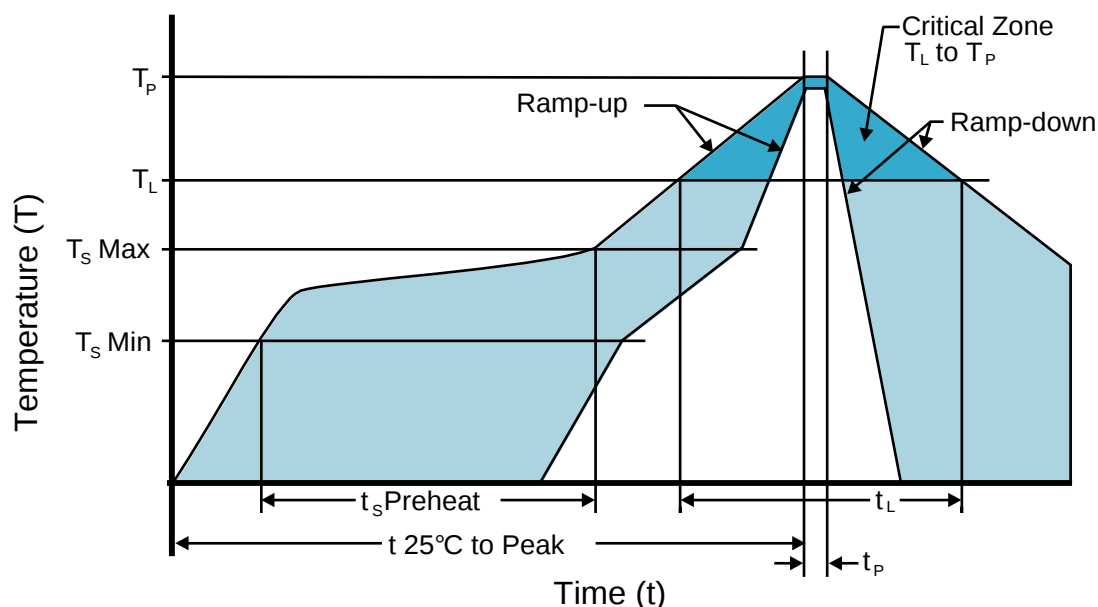
Recommended Solder Reflow Methods



High Temperature Infrared/Convection

T_S MAX to T_L (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T_S MIN)	150°C
- Temperature Typical (T_S TYP)	175°C
- Temperature Maximum (T_S MAX)	200°C
- Time (t_s MIN)	60 - 180 Seconds
Ramp-up Rate (T_L to T_P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T_L)	217°C
- Time (t_L)	60 - 150 Seconds
Peak Temperature (T_P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T_P Target)	250°C +0/-5°C
Time within 5°C of actual peak (t_P)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1

Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

T_S MAX to T_L (Ramp-up Rate) 5°C/second Maximum

Preheat

- Temperature Minimum (T_S MIN) N/A
- Temperature Typical (T_S TYP) 150°C
- Temperature Maximum (T_S MAX) N/A
- Time (t_s MIN) 60 - 120 Seconds

Ramp-up Rate (T_L to T_P) 5°C/second Maximum

Time Maintained Above:

- Temperature (T_L) 150°C
- Time (t_L) 200 Seconds Maximum

Peak Temperature (T_P) 240°C Maximum

Target Peak Temperature (T_P Target) 240°C Maximum 2 Times / 230°C Maximum 1 Time

Time within 5°C of actual peak (t_P) 10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time

Ramp-down Rate 5°C/second Maximum

Time 25°C to Peak Temperature (t) N/A

Moisture Sensitivity Level Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.